查询SN55LBC174供应商

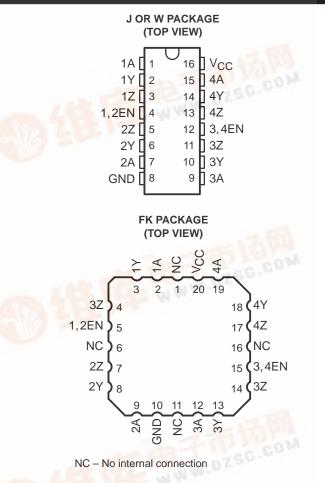
<u>捷多邦,专业PCB打样工厂,24小时加急出SN</u>55LBC174 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

SGLS082 - MARCH 1995

- Meets EIA Standard RS-485
- Designed for High-Speed Multipoint Transmission on Long Bus Lines in Noisy Environments
- Supports Data Rates up to and Exceeding Ten Million Transfers Per Second
- Common-Mode Output Voltage Range of –7 V to 12 V
- Positive- and Negative-Current Limiting
- Low Power Consumption ... 1.5 mA Max (Output Disabled)

description

The SN55LBC174 is composed of monolithic quadruple differential line drivers with 3-state outputs. This device is designed to meet the requirements of the Electronics Industry Association (EIA) Standard RS-485 and is balanced multipoint optimized for bus transmission at data rates up to and exceeding 10 million bits per second. Each driver features wide positive and negative common-mode output voltage ranges, current limiting, and thermal-shutdown protection making it suitable for party-line applications in noisy environments. This device is designed using LinBiCMOS™, facilitating ultra-low power consumption and inherent robustness.



The SN55LBC174 provides positive and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. This device offers optimum performance when used with the SN55LBC173 quadruple line receiver. The SN55LBC174 is available in the 16-pin CDIP package (J), the 16-pin CPAK (W), or the 20-pin LCCC package (FK).

The SN55LBC174 is characterized for operation over the military temperature range of –55°C to 125°C.

FUNCTION TABLE (each driver)							
INPUT	ENABLE	OUTPUTS					
	ENADLE	Y	Z				
Н	Н	Н	L				
L	н	L	н				
Х	L	Z	z				

H = high level, L = low level, X = irrelevant, Z = high impedance (off)



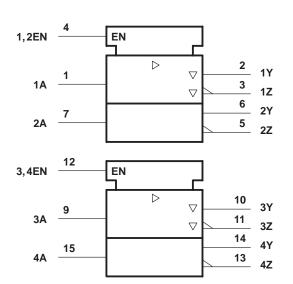
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

BICMOS is a trademark of Texas Instruments Incorporated.



SGLS082 - MARCH 1995

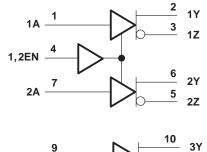
logic symbol[†]

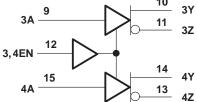


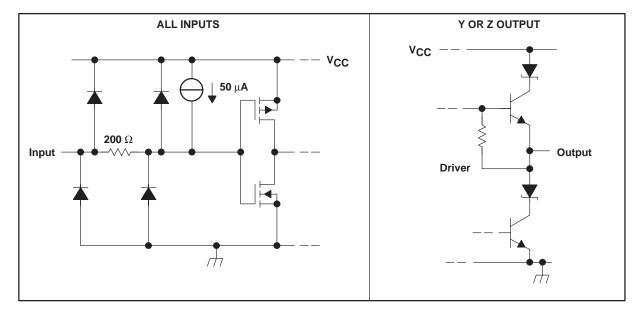
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the J or W package.

schematic of inputs and outputs

logic diagram (positive logic)







SGLS082 - MARCH 1995

absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Supply voltage range, V _{CC} (see Note 1)	–0.3 V to 7 V
Output voltage range, VO	–10 V to 15 V
Input voltage range, V ₁	$\dots \dots $
Continuous power dissipation	internally limited [‡]
Operating free-air temperature range, T _A	–55°C to 125°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	−65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[‡]The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature. NOTE 1: All voltage values are with respect to GND.

> T_A = 125°C $T_{\mbox{\boldmath${\Delta}$}} \leq 25^{\circ} C$ **DERATING FACTOR** PACKAGE **POWER RATING POWER RATING** ABOVE $T_A = 25^{\circ}C$ 11.0 mW/°C FK 1375 mW 275 mW J 1375 mW 11.0 mW/°C 275 mW W 1000 mW 8.0 mW/°C 200 mW

DISSIPATION RATING TABLE

recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}			4.75	5	5.25	V
High-level input voltage, VIH			2			V
Low-level input voltage, VIL					0.8	V
	Y or Z			12	V	
Voltage at any bus terminal (separately or common mode), V_O				-7	v	
High-level output current, IOH	Y or Z				-60	mA
Low-level output current, IOL	Y or Z				60	mA
Operating free-air temperature, T _A			-55		125	°C



SGLS082 - MARCH 1995

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	Input clamp voltage	lj = -18 mA				-1.5	V
IVodi	Differential output voltage‡	RL = 54 Ω,	See Figure 1	1.1	1.8	5	V
		R _L = 60 Ω,	See Figure 2	1.1	1.7	5	v
$\Delta V_{OD} $	Change in magnitude of differential output voltage§					±0.2	V
Voc	Common-mode output voltage	R _L = 54 Ω,	See Figure 1			3 - 1	V
$\Delta V_{OC} $	Change in magnitude of common-mode output voltage§					±0.2	V
lo	Output current with power off	$V_{CC} = 0,$	$V_{O} = -7 V$ to 12 V			±100	μA
IOZ	High-impedance-state output current	$V_{O} = -7 V$ to 12 V				±100	μA
IIH	High-level input current	V ₁ = 2.4 V				-100	μA
۱ _{IL}	Low-level input current	V _I = 0.4 V				-100	μΑ
IOS	Short-circuit output current	$V_{O} = -7 V$ to 12 V				±250	mA
ICC	Supply current (all drivers)	No load	Outputs enabled			7	mA
		NO IOAU	Outputs disabled			1.5	ША

[†] All typical values are at $V_{CC} = 5$ V and $T_A = 25^{\circ}C$.

[‡] The minimum V_{OD} specification does not fully comply with EIA Standard RS-485 at operating temperatures below 0°C. The lower output signal should be used to determine the maximum signal transmission distance.

§ Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

switching characteristics, $V_{CC} = 5 V$

PARAMETER		TEST CONDITIONS		Т _А	MIN	TYP	MAX	UNIT
^t d(OD)	Differential output delay time	RL = 54 Ω,	See Figure 3	25°C	2	11	20	ns
				-55°C to 125°C	2		40	115
^t t(OD)	Differential output transition time	R _L = 54 Ω,	See Figure 3	25°C	4	15	25	ns
				-55°C to 125°C	4		40	
t	Output enable time to high level	R _L = 110 Ω,	See Figure 4	25°C			30	ns
^t PZH				-55°C to 125°C			40	
^t PZL	Output enable time to low level	R _L = 110 Ω,	See Figure 5	25°C			30	ns
				-55°C to 125°C			40	115
^t PHZ	Output disable time from high level	R _L = 110 Ω,	See Figure 4	25°C			50	20
				-55°C to 125°C			90	ns
^t PLZ	Output disable time from low level	R _L = 110 Ω,	See Figure 5	25°C			30	20
				-55°C to 125°C			45	ns



SGLS082 - MARCH 1995

PARAMETER MEASUREMENT INFORMATION

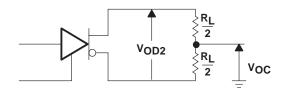


Figure 1. Differential and Common-Mode Output Voltages

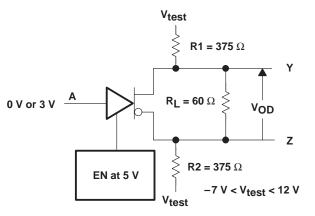
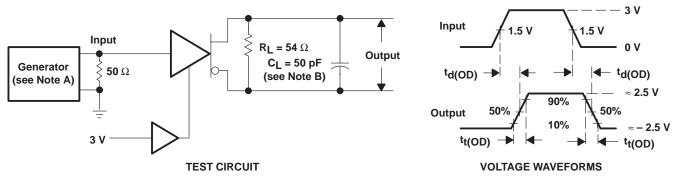


Figure 2. Driver V_{OD} Test Circuit

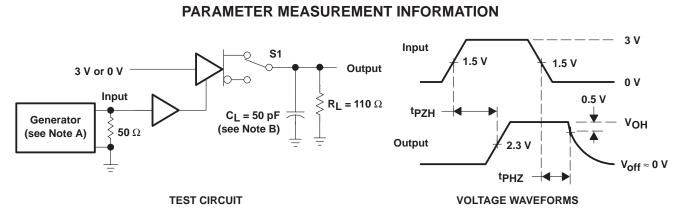


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, t_f \leq 5 ns, t_f \leq 5 ns, Z_O = 50 Ω .
 - B. CL includes probe and stray capacitance.

Figure 3. Driver Differential-Output Test Circuit Delay and Transition-Time Waveforms

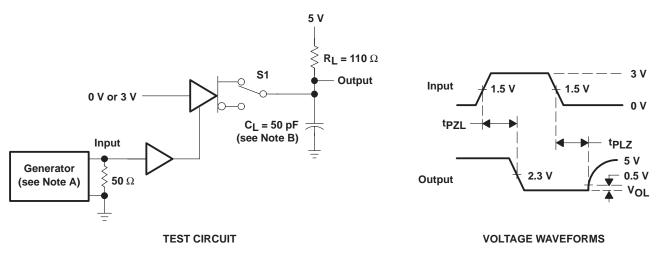


SGLS082 - MARCH 1995



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, t_f \leq 5 ns, t_f \leq 5 ns, Z_O = 50 Ω .
 - B. CL includes probe and stray capacitance.



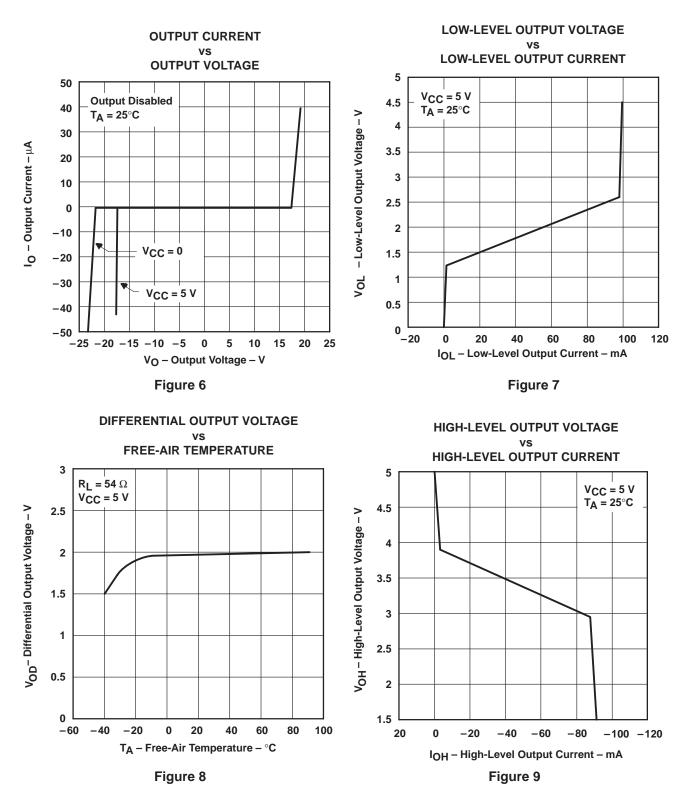


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, t_f \leq 5 ns, t_f \leq 5 ns, Z_O = 50 Ω .
 - B. C_L includes probe and stray capacitance.

Figure 5. t_{PZL} and t_{PLZ} Test Circuit and Waveforms



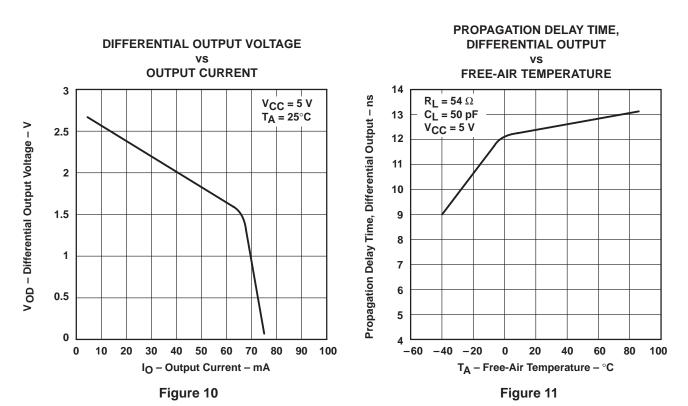
SGLS082 - MARCH 1995



TYPICAL CHARACTERISTICS



SGLS082 - MARCH 1995



TYPICAL CHARACTERISTICS



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated